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SEMICONDUCTOR

April 2009

# SG6742HL/HR Highly Integrated Green-Mode PWM Controller

### Features

- High-Voltage Startup
- Low Operating Current: 2.7mA
- Linearly Decreasing PWM Frequency to 22KHz
- Frequency Hopping to Reduce EMI Emission
- Fixed PWM Frequency: 100KHz
- Peak-Current-Mode Control
- Cycle-by-Cycle Current Limiting
- Leading-Edge Blanking (LEB)
- Synchronized Slope Compensation
- Internal Open-Loop Protection
- GATE Output Maximum Voltage Clamp: 18V
- V<sub>DD</sub> Under-Voltage Lockout (UVLO)
- V<sub>DD</sub> Over-Voltage Protection (OVP)
- Programmable Over-Temperature Protection (OTP)
- Internal Latch Circuit (OVP, OTP)
- Internal-Sense, Short-Circuit Protection
- Built-in 6ms Soft-Start Function
- Constant Power Limit (Full AC Input Range)
- Internal OTP Sensor with Hysteresis

# **Applications**

General-purpose switch-mode power supplies and flyback power converters, including:

- Power Adapters
- Open-Frame SMPS

**Ordering Information** 

## Description

The highly integrated SG6742HL/HR PWM controller provides several features to enhance the performance of flyback converters.

To minimize standby power consumption, a proprietary green-mode function provides off-time modulation to linearly decrease the switching frequency at light-load conditions. To avoid acoustic-noise problems, the minimum PWM frequency is set above 22KHz. This green-mode function enables the power supply to meet international power conservation requirements. With the internal high-voltage startup circuitry, the power loss due to bleeding resistors is eliminated. To further reduce power consumption, SG6742HL/HR is manufactured using the BiCMOS process, which allows an operating current of 2.7mA.

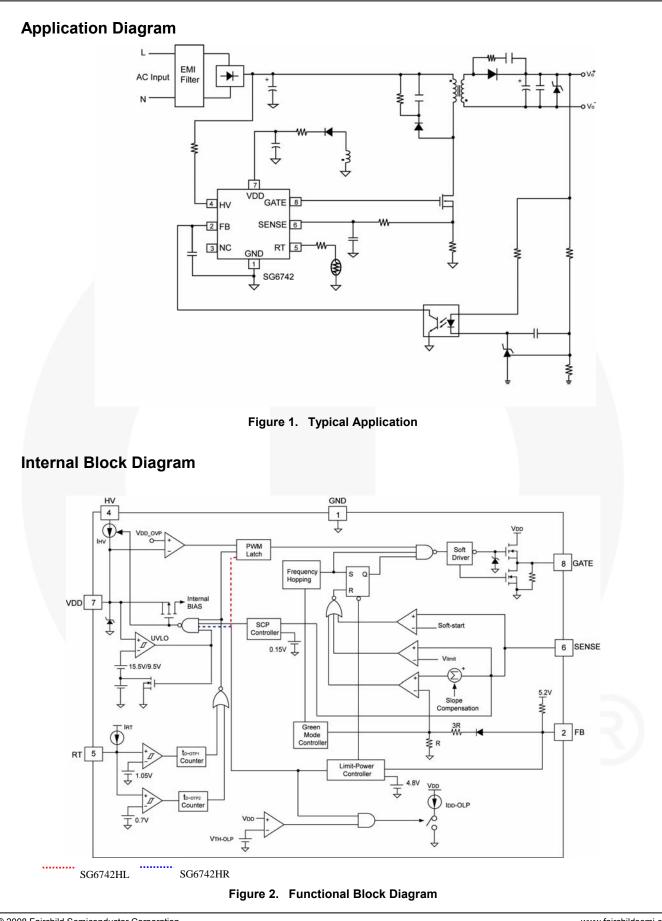
SG6742HL/HR integrates a frequency-hopping function internally that helps reduce EMI emission of a power supply with minimum line filters. Its built-in synchronized slope compensation achieves stable peak-current-mode control. The proprietary, internal line compensation ensures constant output power limit over a wide AC input voltage range, from  $90V_{AC}$  to  $264V_{AC}$ .

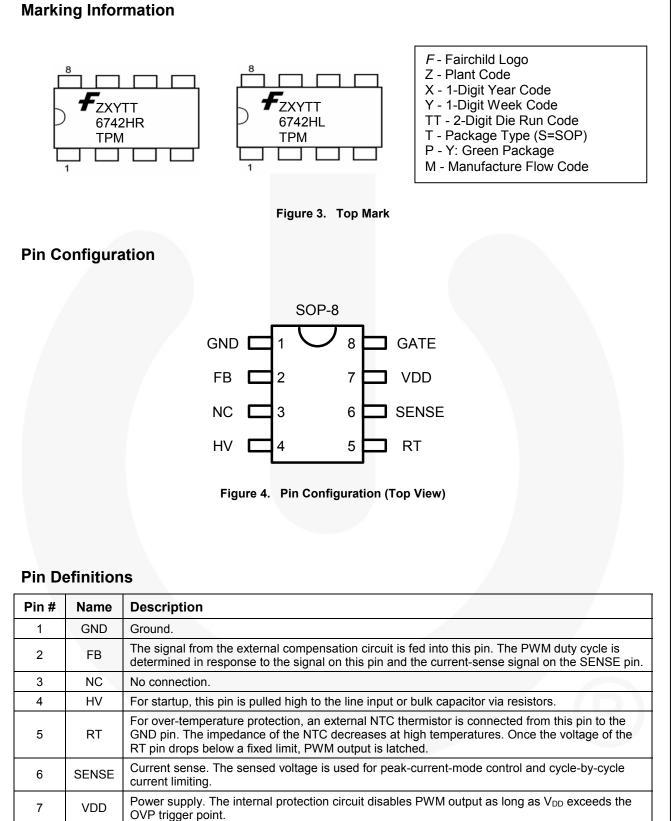
SG6742HL/HR provides many protection functions. In addition to cycle-by-cycle current limiting, the internal open-loop protection circuit ensures safety should an open-loop or output short-circuit failure occur. PWM output is disabled until V<sub>DD</sub> drops below the UVLO lower limit, when the controller starts up again. As long as V<sub>DD</sub> exceeds ~25V, the internal OVP circuit is triggered.

SG6742HL/HR is available in an 8-pin SOP package.

Part Number	Operating Temperature Range	OLP Function	Package	Eco Status	Packing Method
SG6742HLSY	-40 to +105°C	Latch	8-Lead Small Outline Package (SOP)	Green	Tape & Reel
SG6742HRSY	-40 to +105°C	Restart	8-Lead Small Outline Package (SOP)	Green	Tape & Reel

Ø For Fairchild's definition of "green" Eco Status, please visit: <u>http://www.fairchildsemi.com/company/green/rohs\_green.html</u>.





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The totem-pole output driver. Soft driving waveform is implemented for improved EMI.

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# **Absolute Maximum Ratings**

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Min.	Max.	Unit	
V <sub>VDD</sub>	DC Supply Voltage <sup>(1, 2)</sup>			30	V
V <sub>FB</sub>	FB Pin Input Voltage		-0.3	7.0	V
V <sub>SENSE</sub>	SENSE Pin Input Voltage		-0.3	7.0	V
V <sub>RT</sub>	RT Pin Input Voltage		-0.3	7.0	V
V <sub>HV</sub>	HV Pin Input Voltage			500	V
PD	Power Dissipation ( $T_A < 50^{\circ}C$ )			400	mW
$\Theta_{JA}$	Thermal Resistance (Junction-to-Air)			141	°C/W
TJ	Operating Junction Temperature		-40	+125	°C
T <sub>STG</sub>	Storage Temperature Range		-55	+150	°C
TL	Lead Temperature (Wave Soldering	or IR, 10 Seconds)		+260	°C
ESD	Human Body Model, JEDEC:JESD22-A114	All pins except HV pin		4.0	kV
ESD	Charged Device Model, JEDEC:JESD22-C101	All pins except HV pin		1.5	ĸv

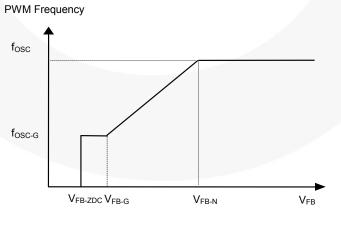
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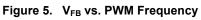
1. All voltage values, except differential voltages, are given with respect to the network ground terminal.

2. Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device.

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
V <sub>DD</sub> Secti	on					
VOP	Continuously Operating Voltage				22	V
V <sub>DD-ON</sub>	Start Threshold Voltage		14.5	15.5	16.5	V
$V_{\text{DD-OFF}}$	Minimum Operating Voltage		8.5	9.5	10.5	V
I <sub>DD-ST</sub>	Startup Current	V <sub>DD-ON</sub> – 0.16V			30	μA
I <sub>DD-OP</sub>	Operating Supply Current	V <sub>DD</sub> =15V, GATE Open		2.7	3.7	mA
I <sub>DD-OLP</sub>	Internal Sink Current	V <sub>TH-OLP</sub> +0.1V	30	60	90	μA
$V_{\text{TH-OLP}}$	IDD-OLP off Voltage		6.5	7.5	8.0	V
$V_{\text{DD-OVP}}$	V <sub>DD</sub> Over-Voltage Protection		24	25	26	V
t <sub>D-VDDOVP</sub>	V <sub>DD</sub> Over-Voltage Protection Debounce Time		75	125	200	μs
HV Section	on					
I <sub>HV</sub>	Supply Current from HV Pin	V <sub>AC</sub> =90V (V <sub>DC</sub> =120V), V <sub>DD</sub> =0V	1.75	2.30	3.35	mA
I <sub>HV-LC</sub>	Leakage Current After Startup	HV=500V, V <sub>DD</sub> =V <sub>DD-</sub> <sub>OFF</sub> +1V		1	20	μA
Oscillato	r Section					
4		Center Frequency	90	100	110	
f <sub>osc</sub>	Frequency in Normal Mode	Hopping Range	±4.2	±4.7	±5.2	KHz
t <sub>HOP</sub>	Hopping Period		4.9	5.6	6.3	ms
f <sub>OSC-G</sub>	Green-Mode Frequency		18	22	25	KHz
$\mathbf{f}_{DV}$	Frequency Variation vs. V <sub>DD</sub> Deviation	V <sub>DD</sub> =11V to 22V			5	%
f <sub>DT</sub>	Frequency Variation vs. Temperature Deviation	T <sub>A</sub> =-40 to 105°C			5	%

Continued on the following page...





**Electrical Characteristics** 

# Electrical Characteristics (Continued)

 $V_{DD}$ =15V and T<sub>A</sub>=25°C unless otherwise noted.

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
Feedback	Input Section	·	•			
Av	Input Voltage to Current-Sense Attenuation		1/4.15	1/4.00	1/3.85	V/V
Z <sub>FB</sub>	Input Impedance		4		7	kΩ
$V_{\text{FB-OPEN}}$	Output High Voltage	FB Pin Open		5.2		V
$V_{\text{FB-OLP}}$	FB Open-Loop Trigger Level		4.6	4.8	5.0	V
t <sub>D-OLP</sub>	Delay Time of FB Pin Open-loop Protection		50	56	62	ms
$V_{FB-N}$	Green-Mode Entry FB Voltage		3.1	3.3	3.5	V
$V_{FB-G}$	Green-Mode Ending FB Voltage			V <sub>FB-N</sub> - 0.5		V
V <sub>FB-ZDC</sub>	Zero Duty-Cycle Input Voltage			1.6		V
Current-S	ense Section				I	
Z <sub>SENSE</sub>	Input Impedance			12		KΩ
VSTHFL	Current Limit Flatten Threshold Voltage	Duty cycle=45%	0.97	1.00	1.03	V
VSTHVA	Current Limit Valley Threshold Voltage	VSTHFL-VSTHVA	0.27	0.30	0.33	V
t <sub>PD</sub>	Delay to Output			100	200	ns
t <sub>LEB</sub>	Leading-Edge Blanking Time		100	140	180	ns
V <sub>S-SCP</sub>	Threshold Voltage for SENSE Short-Circuit F	Protection	0.10	0.15	0.20	V
t <sub>D-SSCP</sub>	Delay Time for SENSE Short-Circuit Protection	V <sub>SENSE</sub> <0.15V	100	150	200	μs
t <sub>ss</sub>	Period During Soft-Startup Time	Startup Time	5	6	7	ms
GATE Sec	tion					
DCY <sub>MAX</sub>	Maximum Duty Cycle		60	65	70	%
V <sub>GATE-L</sub>	Gate Low Voltage	V <sub>DD</sub> =15V, I <sub>O</sub> =50mA			1.5	V
V <sub>GATE-H</sub>	Gate High Voltage	V <sub>DD</sub> =12V, I <sub>O</sub> =50mA	8			V
tr	Gate Rising Time	V <sub>DD</sub> =15V, C <sub>L</sub> =1nF	150	250	350	ns
t <sub>f</sub>	Gate Falling Time	$V_{DD}$ =15V, CL=1nF	30	50	90	ns
I <sub>GATE-</sub>	Gate Source Current	V <sub>DD</sub> =15V, GATE=6V	250			mA
IGATE-SINK	Gate Sink Current	V <sub>DD</sub> =15V, GATE=1V	300			mA
V <sub>GATE-</sub>	Gate Output Clamping Voltage	V <sub>DD</sub> =22V			18	V
RT Sectio	n					1
R <sub>RT</sub>	Internal Resistor from RT Pin		10.08	10.50	10.92	KΩ
V <sub>RTTH1</sub>	Over-Temperature Protection Threshold	$0.7V < V_{RT} < 1.05V$ , After 12ms Latch Off	1.015	1.050	1.085	V
V <sub>RTTH2</sub>	Voltage	$V_{RT} < 0.7V$ , After 100µs Latch Off	0.65	0.70	0.75	V
t <sub>D-OTP1</sub>		V <sub>RTTH2</sub> < V <sub>RT</sub> < V <sub>RTTH1</sub>	16	20	24	ms
t <sub>D-OTP2</sub>	Over-Temperature Latch-off Debounce	V <sub>RT</sub> < V <sub>RTTH2</sub>	90	130	170	μs
	perature Protection Section (OTP)		-			
Тотр	Protection Junction Temperature <sup>(3)</sup>			+135		°C
011	Restart Junction Temperature <sup>(4)</sup>		<u> </u>	Тотр-25		°C

Notes:

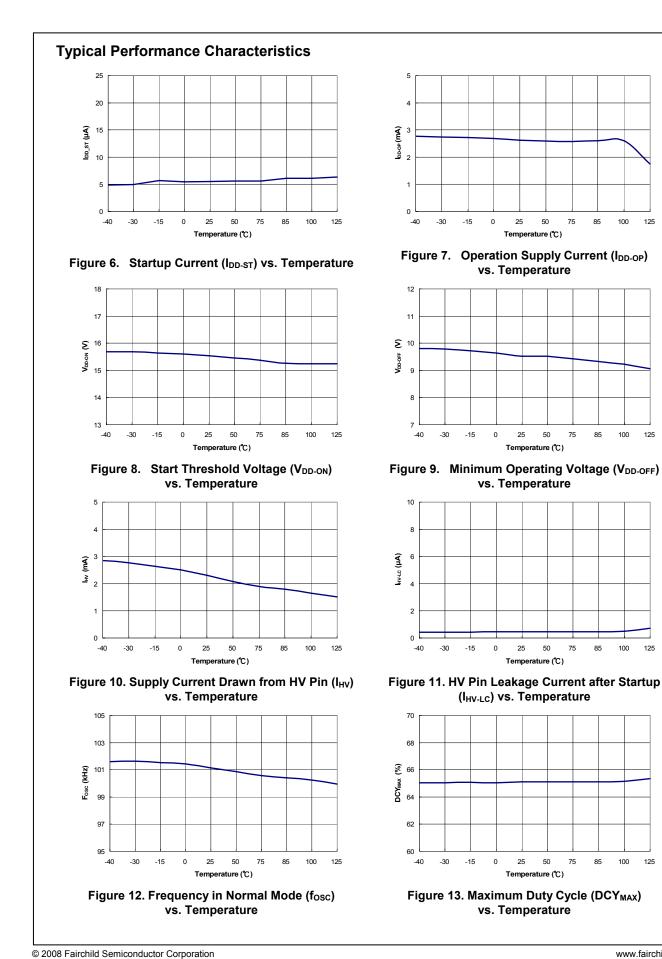
3.

When activated, the output is disabled and the latch is turned off. The threshold temperature for enabling the output again and resetting the latch after OTP has been activated. 4.

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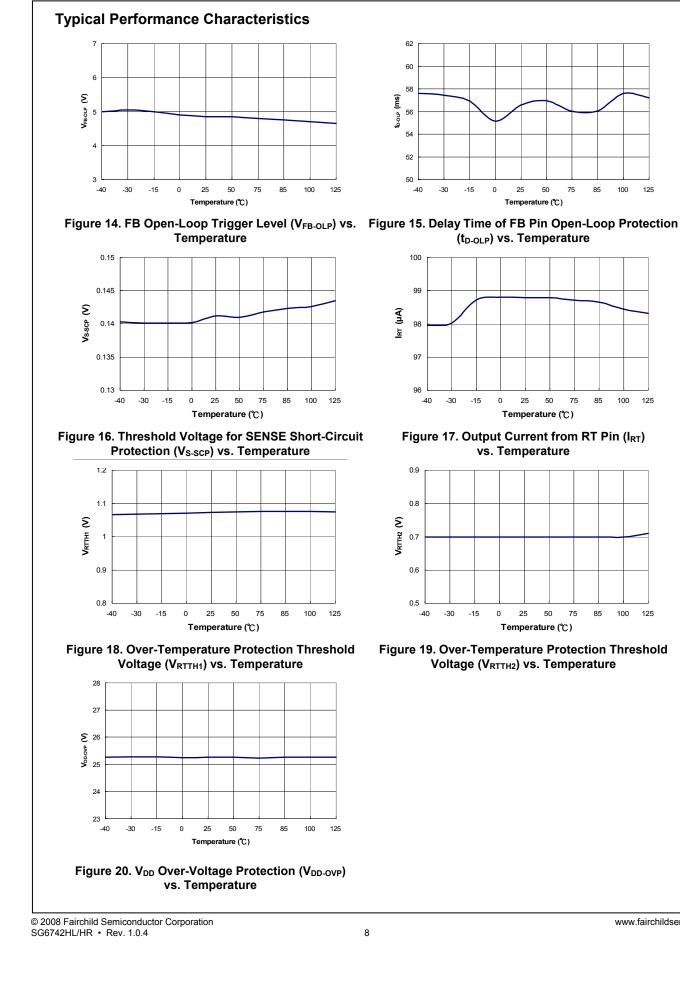




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# **Functional Description**

### **Startup Current**

For startup, the HV pin is connected to the line input or bulk capacitor through an external diode and resistor,  $R_{HV}$ , (1N4007 / 100K $\Omega$  recommended). Typical startup current drawn from pin HV is 2.3mA and charges the hold-up capacitor through the diode and resistor. When the  $V_{DD}$  capacitor level reaches  $V_{DD-ON}$ , the startup current switches off. At this moment, the  $V_{DD}$  capacitor only supplies the SG6742HL/HR to keep the  $V_{DD}$  before the auxiliary winding of the main transformer to provide the operating current.

### **Operating Current**

Operating current is around 2.7mA. The low operating current enables better efficiency and reduces the requirement of  $V_{DD}$  hold-up capacitance.

### **Green-Mode Operation**

The proprietary green-mode function provides an offtime modulation to reduce the switching frequency in the light-load and no-load conditions. The on time is limited for better abnormal or brownout protection.  $V_{FB}$ , which is derived from the voltage feedback loop, is taken as the reference. Once  $V_{FB}$  is lower than the threshold voltage, switching frequency is continuously decreased to the minimum green-mode frequency of around 22KHz.

### **Current Sensing / PWM Current Limiting**

Peak-current-mode control is utilized to regulate output voltage and provide pulse-by-pulse current limiting. The switch current is detected by a sense resistor into the SENSE pin. The PWM duty cycle is determined by this current sense signal and V<sub>FB</sub>, the feedback voltage. When the voltage on SENSE pin reaches around  $V_{COMP}$ =(V<sub>FB</sub>-0.6)/4, a switch cycle is terminated immediately.  $V_{COMP}$  is internally clamped to a variable voltage around 0.85V for output power limit.

### Leading-Edge Blanking (LEB)

Each time the power MOSFET is switched on, a turn-on spike occurs on the sense-resistor. To avoid premature termination of the switching pulse, a leading-edge blanking time is built in. During this blanking period, the current-limit comparator is disabled and cannot switch off the gate driver.

### Under-Voltage Lockout (UVLO)

The turn-on and turn-off thresholds are fixed internally at 15.5V and 9.5V. During startup, the hold-up capacitor must be charged to 15.5V through the startup resistor to enable the IC. The hold-up capacitor continues to supply  $V_{DD}$  before the energy can be delivered from auxiliary winding of the main transformer.  $V_{DD}$  must not drop below 9.5V during this startup process. This UVLO hysteresis window ensures that hold-up capacitor is adequate to supply  $V_{DD}$  during startup.

### Gate Output / Soft Driving

The BiCMOS output stage is a fast totem-pole gate driver. Cross conduction has been avoided to minimize heat dissipation, increase efficiency, and enhance reliability. The output driver is clamped by an internal 18V Zener diode to protect power MOSFET transistors against undesirable gate over voltage. A soft driving waveform is implemented to minimize EMI.

### Soft-Start

For many applications, it is necessary to minimize the inrush current at startup. The built-in 6ms soft-start circuit significantly reduces the startup current spike and output voltage overshoot.

### **Built-in Slope Compensation**

The sensed voltage across the current-sense resistor is used for peak-current-mode control and pulse-by-pulse current limiting. Built-in slope compensation improves stability and prevents sub-harmonic oscillation. SG6742HL/HR inserts a synchronized positive-going ramp at every switching cycle.

### **Constant Output Power Limit**

When the SENSE voltage, across the sense resistor  $R_S$ , reaches the threshold voltage, around 1V, the output GATE drive is turned off after a small delay,  $t_{PD}$ . This delay introduces an additional current proportional to  $t_{PD} \cdot V_{IN} / L_P$ . Since the delay is nearly constant regardless of the input voltage  $V_{IN}$ , higher input voltage results in a larger additional current and the output power limit is higher than under low input line voltage. To compensate this variation for wide AC input range, a sawtooth power-limiter is designed to solve the unequal power-limit problem. The power limiter is designed as a positive ramp signal fed to the inverting input of the OCP comparator. This results in a lower current limit at high-line inputs than at low-line inputs.

### **V**<sub>DD</sub> Over-Voltage Protection (OVP)

 $V_{\text{DD}}$  over-voltage protection has been built in to prevent damage due to abnormal conditions. If the  $V_{\text{DD}}$  voltage is over the over-voltage protection voltage ( $V_{\text{DD-OVP}}$ ) and lasts for  $t_{\text{D-VDDOVP}}$ , the PWM pulses are disabled until the  $V_{\text{DD}}$  voltage drops below the UVLO, then starts again. Over-voltage conditions are usually caused by open feedback loops.

### Functional Description (Continued)

### **Thermal Protection**

An NTC thermistor,  $R_{NTC}$ , in series with a resistor  $R_A$ , can be connected from the RT pin to ground. A constant current  $I_{RT}$  is output from the RT pin. The voltage on the RT pin can be expressed as  $V_{RT} = I_{RT} \cdot (R_{NTC} + R_A)$ , where  $I_{RT}$  is 100µA. At high ambient temperatures,  $R_{NTC}$  is smaller, such that  $V_{RT}$  decreases. When  $V_{RT}$  is less than 1.05V ( $V_{RTTH1}$ ), the PWM turns off after 20ms ( $t_{D-OTP1}$ ). If  $V_{RT}$  is less than 0.7V ( $V_{RTTH2}$ ), PWM turns off immediately after 130µs ( $t_{D-OTP2}$ ).

### **Limited Power Control**

The FB voltage increases every time the output of the power supply is shorted or overloaded. If the FB voltage remains higher than a built-in threshold for longer than  $t_{D-OLP}$ , PWM output is turned off. As PWM output is turned off,  $V_{DD}$  begins decreasing.

When  $V_{DD}$  goes below the turn-off threshold (~9.5V) the controller is totally shut down.  $V_{DD}$  is charged up to the turn-on threshold voltage of 15.5V through the startup resistor until PWM output is restarted. This protection feature continues as long as the overloading condition persists. This prevents the power supply from overheating due to overloading conditions. When  $V_{RT}$  is less than 1.05V ( $V_{RTTH1}$ ), the PWM is turned off after 20ms ( $t_{D-OTP1}$ ). If  $V_{RT}$  is less than 0.7V ( $V_{RTTH2}$ ), PWM is turned off immediately after 130µs ( $t_{D-OTP2}$ ).

### **Noise Immunity**

Noise on the current sense or control signal may cause significant pulse-width jitter, particularly in continuous-conduction mode. Slope compensation helps alleviate this problem. Good placement and layout practices should be followed. Avoiding long PCB traces and component leads, locating compensation and filter components near the SG6742HL/HR, and increasing the power MOS gate resistance improve performance.

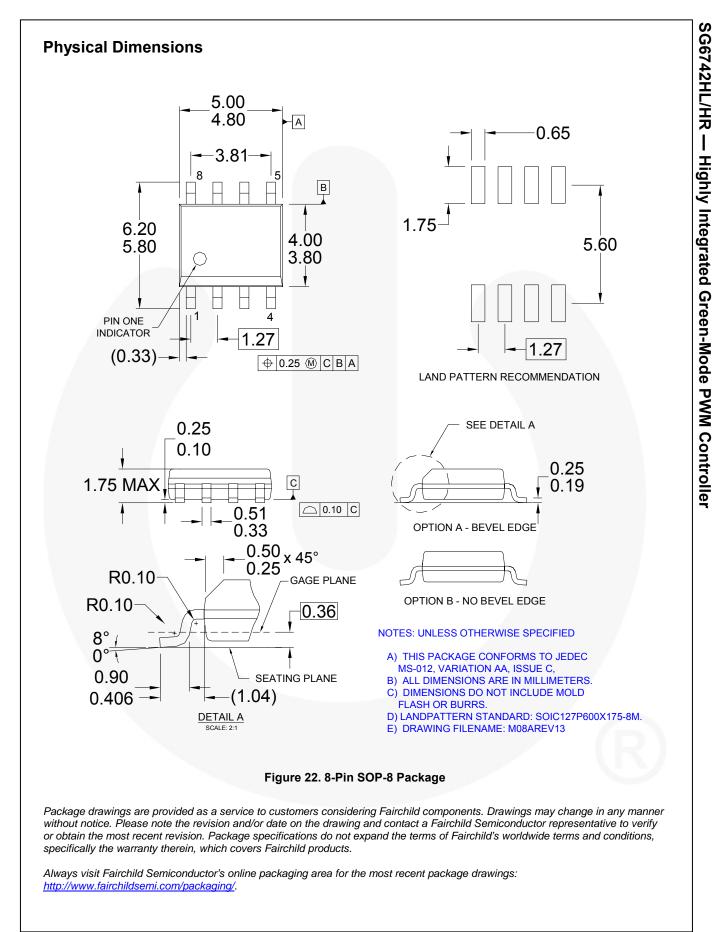
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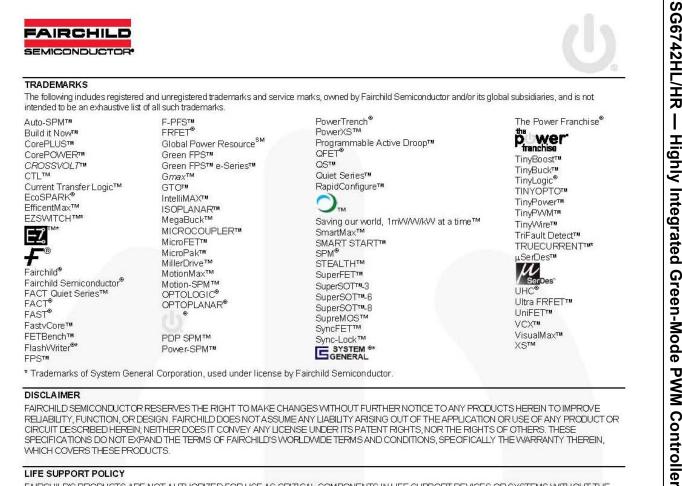
Figure 21. 60W Flyback 12V/5A Application Circuit

### BOM

Designator	Part Type	Designator	Part Type	
BD1	BD 4A/600V	L3	Inductor (900µH)	
C1	XC 0.68µF/300V	Q1	STP20-100CT	
C2	XC 0.1µF/300V	Q2	MOS 7A/600V	
C3	YC 2200pF/Y1	R1	R 100KΩ 1/2W	
C4	EC 120µF/400V	R2	R 47Ω 1/4W	
C5	CC 0.01µF/500V	R3	R 100KΩ 1/2W	
C6	CC 1000pF/100V	R4	R 4.7Ω 1/8W	
C7	EC 1000µF/25V	R5	R 100Ω 1/8W	
C8	EC 470µF/25V	R6, R9	R 4.7KΩ 1/8W	
C9	EC 22µF/50V	R7	R 0.3Ω 2W	
C10	CC 47pF/50V	R8	R 680Ω 1/8W	
C11	CC 2200pF/50V	R10	R 150KΩ 1/8W	
C12	CC 0.01µF/50V	R11	R 39KΩ 1/8W	
D1	Zener Diode 15V 1/2W (option)	THER1	Thermistor TTC104	
D2	BYV95C	T1	10mH	
D3	FR103	T2	255µH(PQ2620)	
D4	1N4007	U1	IC SG6742	
F1	FUSE 4A/250V	U2	IC PC817	
L1	Inductor (900µH)	U3	IC TL431	
L2	Inductor (2µH)	VZ1	VZ 9G	

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